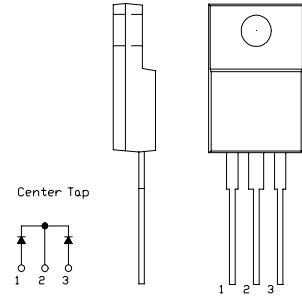


# SBD Type : FCH20B10

OUTLINE DRAWING

**FEATURES**

- \*TO-220AB Case
- \*Fully Molded
- \*Dual Diodes – Cathode Common
- \*Low Forward Voltage Drop
- \*High Surge Capability
- \*Tj=150 °C operation



## Maximum Ratings

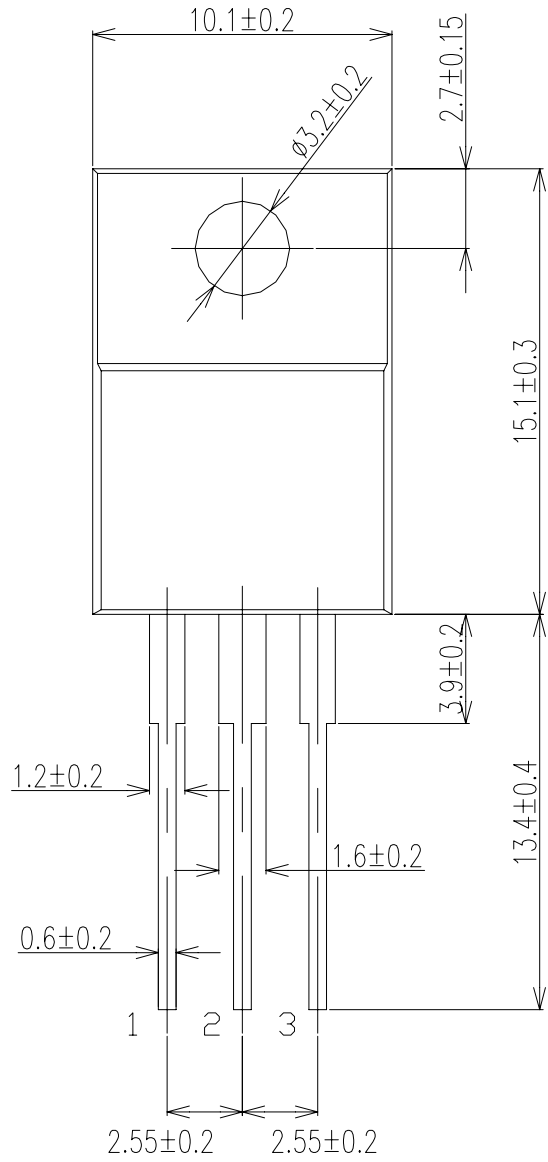
Approx Net Weight: 1.75g

Rating	Symbol	FCH20B10		Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$	100		V
Average Rectified Output Current	$I_O$	20	Tc=105°C 50 Hz Full Sine Wave Resistive Load	A
RMS Forward Current	$I_{F(RMS)}$	22.2		A
Surge Forward Current	$I_{FSM}$	180	50Hz Full Sine Wave ,1cycle Non-repetitive	A
Operating JunctionTemperature Range	$T_{jw}$	-40 to +150		°C
Storage Temperature Range	$T_{stg}$	-40 to +150		°C
Mounting torque	Ftor	recommended torque = 0.5		N•m

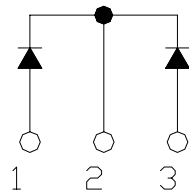
## Electrical • Thermal Characteristics

Characteristics	Symbol	Conditions	Min.	Typ.	Max.	Unit
Peak Reverse Current	$I_{RM}$	Tj= 25°C, $V_{RM}= V_{RRM}$ per Arm	-	-	1	mA
Peak Forward Voltage	$V_{FM}$	Tj= 25°C, $I_{FM}= 10 A$ per Arm	-	-	0.91	V
Thermal Resistance	Rth(j-c)	Junction to Case	-	-	2.3	°C /W
	Rth(c-f)	Cace to Fin	-	-	1.5	°C /W

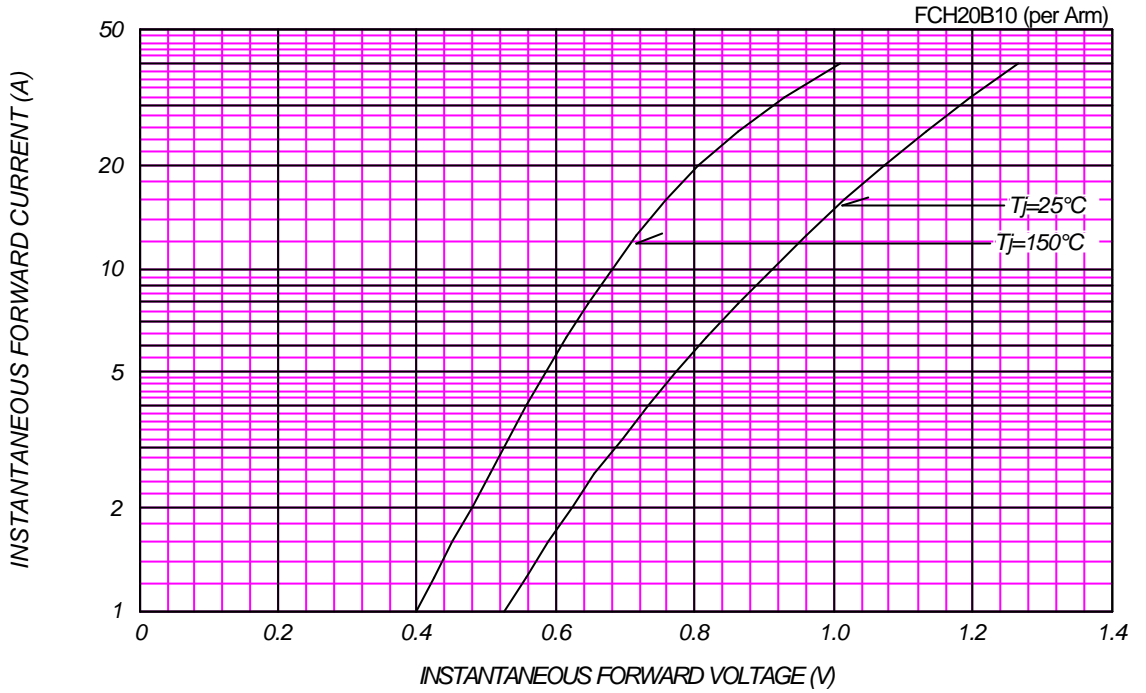
FCH\_B\_ OUTLINE DRAWING (Dimensions in mm)



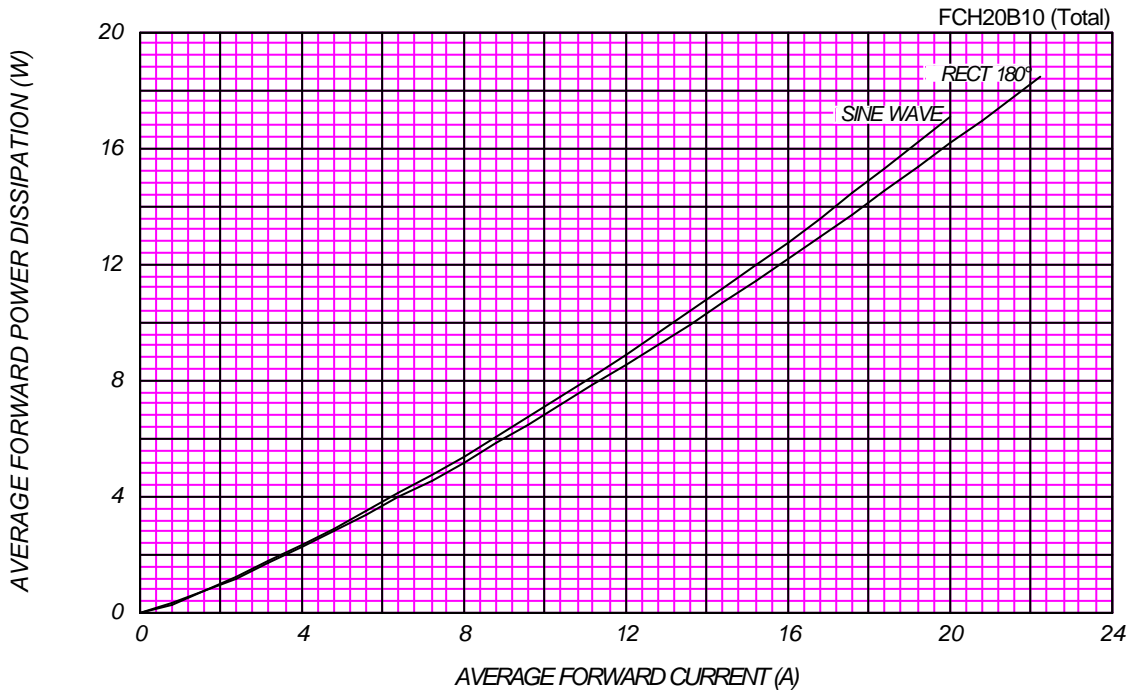
Center Tap



### FORWARD CURRENT VS. VOLTAGE

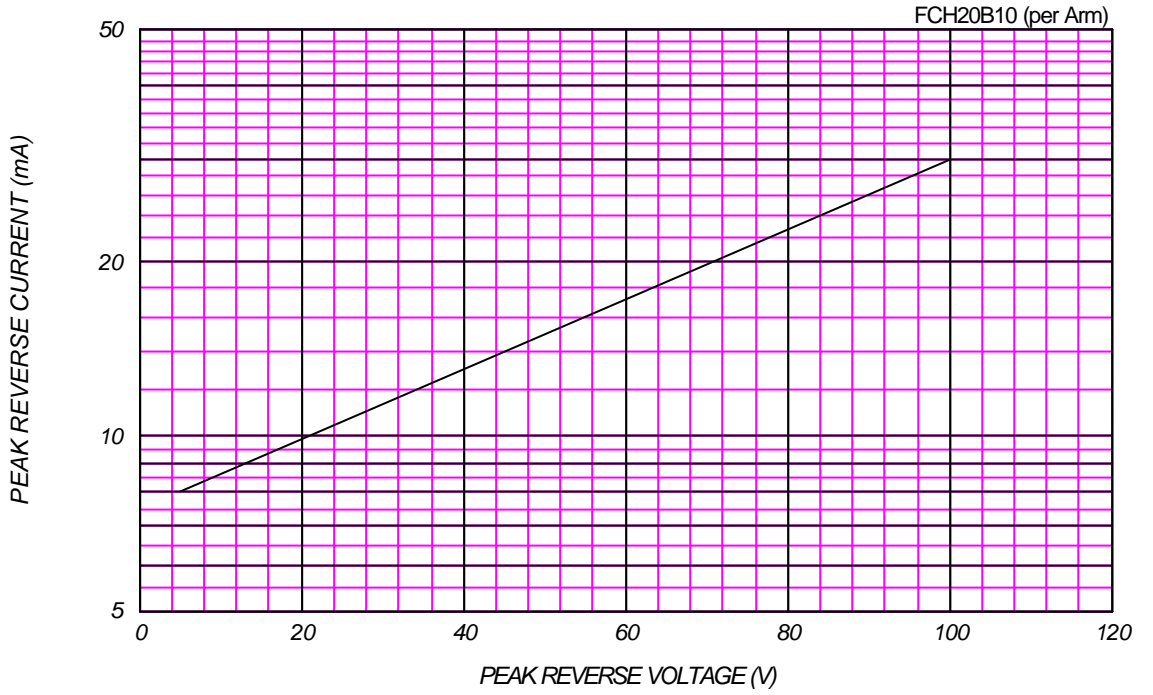


### AVERAGE FORWARD POWER DISSIPATION

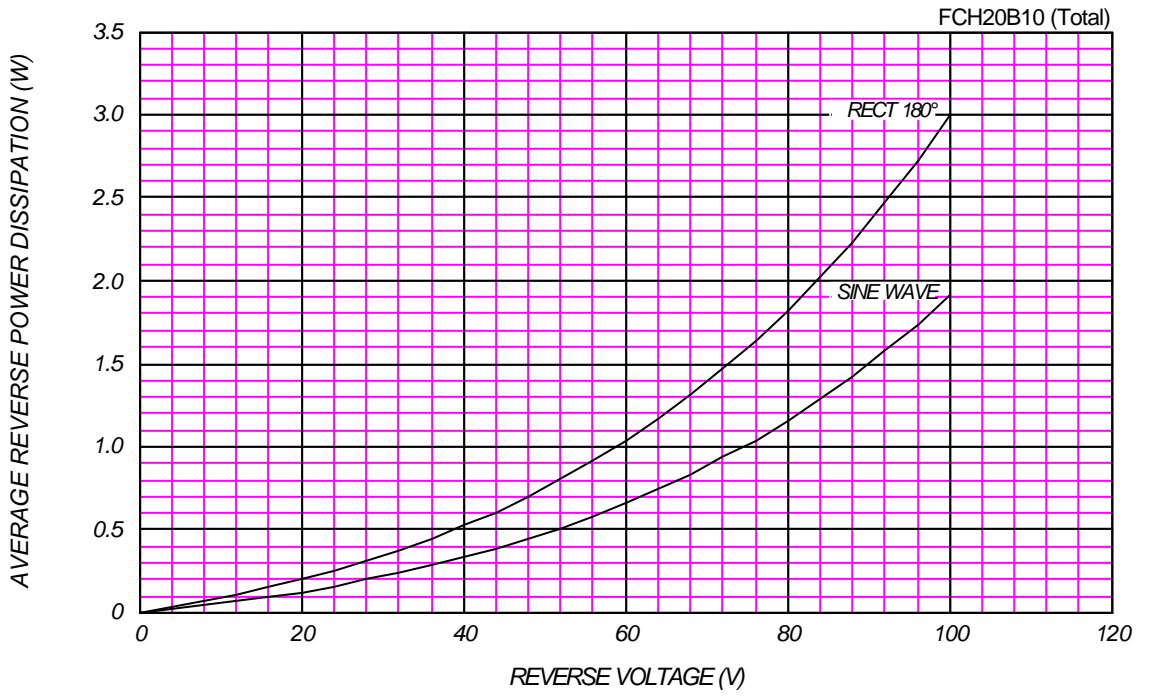


PEAK REVERSE CURRENT VS. PEAK REVERSE VOLTAGE

T<sub>j</sub> = 150 °C



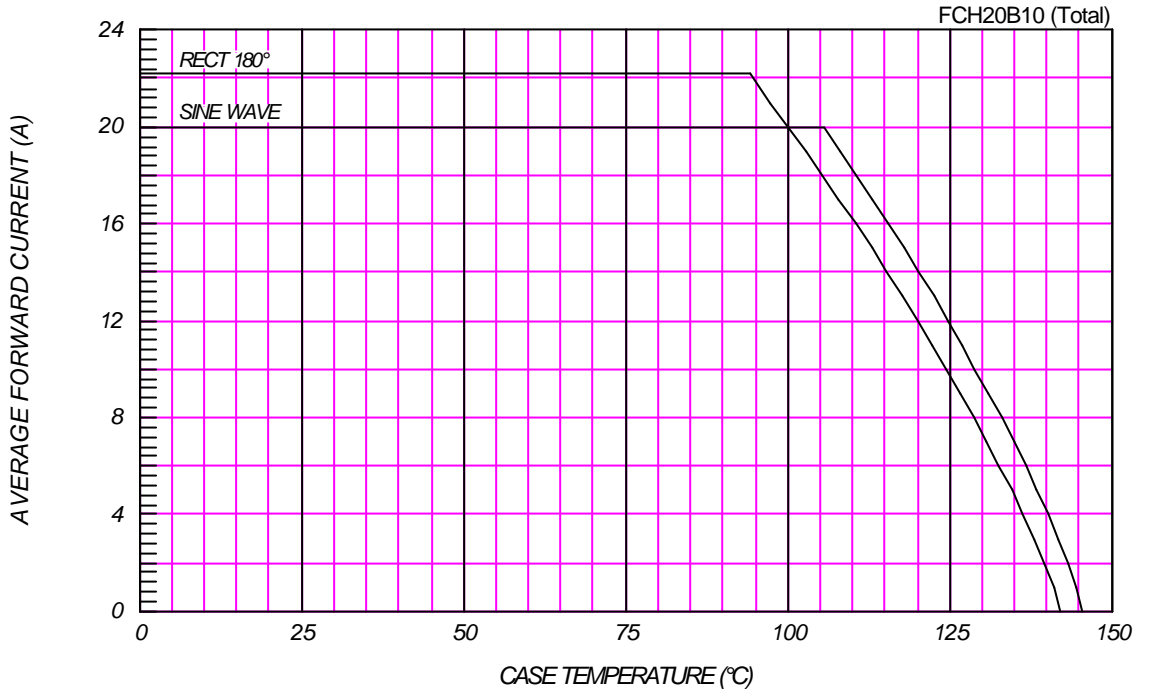
AVERAGE REVERSE POWER DISSIPATION





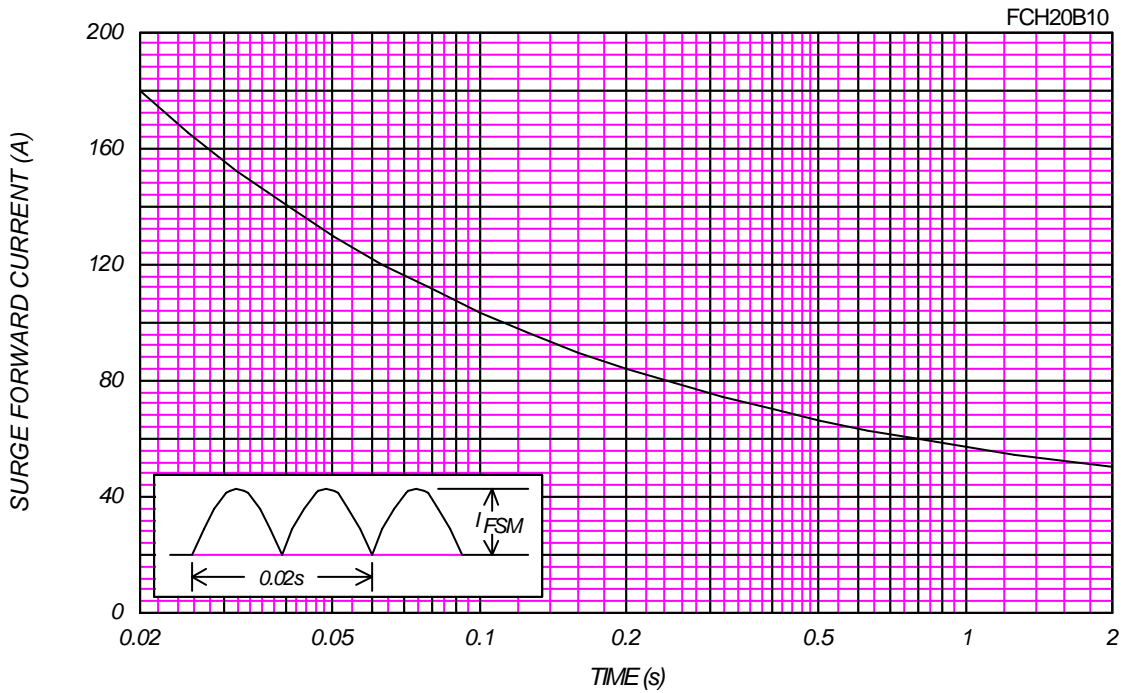
### AVERAGE FORWARD CURRENT VS. CASE TEMPERATURE

$V_{RM} = 100V$



### SURGE CURRENT RATINGS

f=50Hz, Sine Wave, Non-Repetitive, No Load



### JUNCTION CAPACITANCE VS. REVERSE VOLTAGE

$T_j=25^\circ\text{C}$ ,  $V_m=20\text{mV}_{\text{RMS}}$ ,  $f=100\text{kHz}$ , Typical Value

